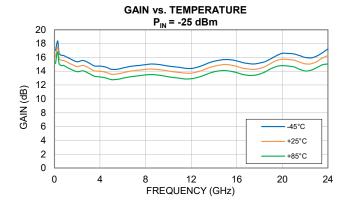
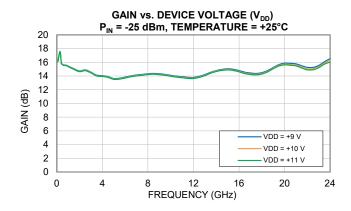
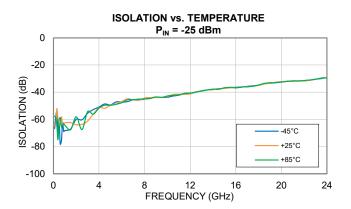
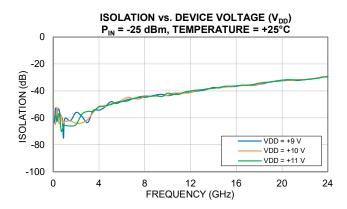
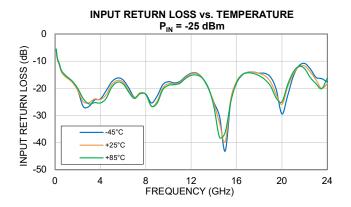
Note: Data over temperature was taken at V_{DD} = +10 V. At +25°C, V_{GG1} has been adjusted to achieve I_{DD} = 300 mA. V_{GG1} was not adjusted at -45°C or +85°C. For over voltage data, V_{GG1} was adjusted until I_{DD} = 300 mA at all V_{DD} levels specified. All data taken with $V_{GG2} = +3.5 \text{ V}$.

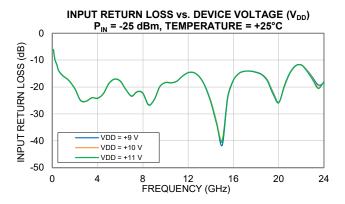




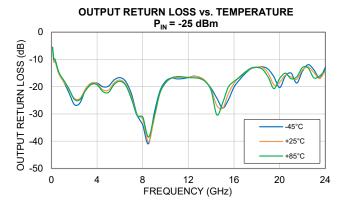


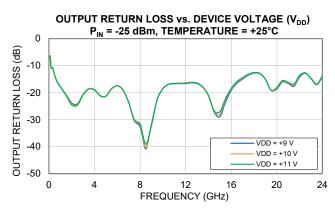


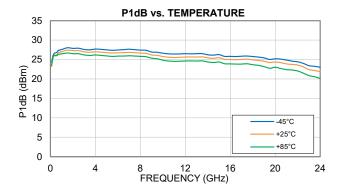


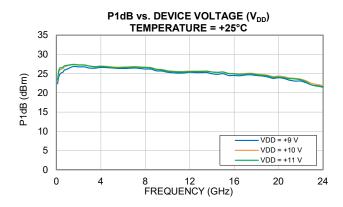


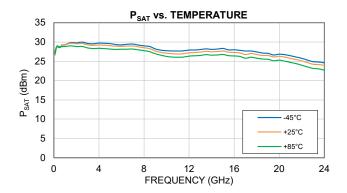
Note: Data over temperature was taken at V_{DD} = +10 V. At +25°C, V_{GG1} has been adjusted to achieve I_{DD} = 300 mA. V_{GG1} was not adjusted at -45°C or +85°C. For over voltage data, V_{GG1} was adjusted until I_{DD} = 300 mA at all V_{DD} levels specified. All data taken with V_{GG2} = +3.5 V.

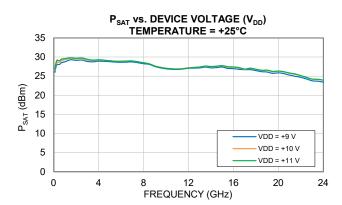




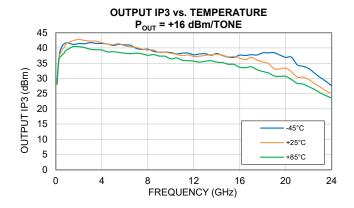


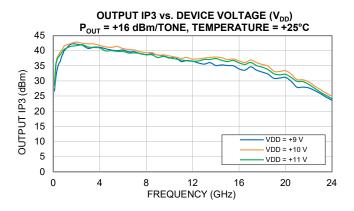


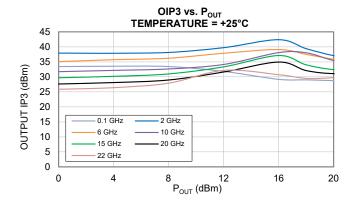


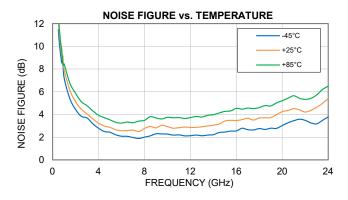


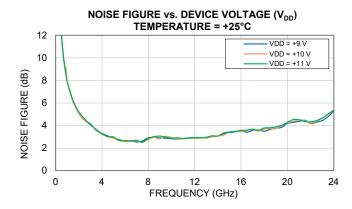
Note: Data over temperature was taken at V_{DD} = +10 V. At +25°C, V_{GG1} has been adjusted to achieve I_{DD} = 300 mA. V_{GG1} was not adjusted at -45°C or +85°C. For over voltage data, V_{GG1} was adjusted until I_{DD} = 300 mA at all V_{DD} levels specified. All data taken with V_{GG2} = +3.5 V.

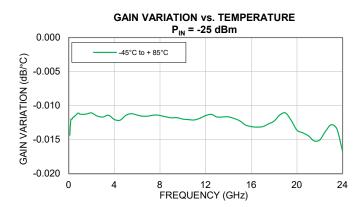




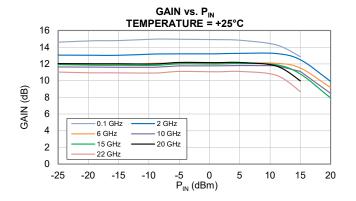


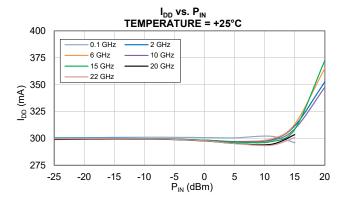






Note: Data over temperature was taken at V_{DD} = +10 V. At +25°C, V_{GG1} has been adjusted to achieve I_{DD} = 300 mA. V_{GG1} was not adjusted at -45°C or +85°C. For over voltage data, V_{GG1} was adjusted until I_{DD} = 300 mA at all V_{DD} levels specified. All data taken with V_{GG2} = +3.5 V.







Note: Data was taken at V_{DD} = +10 V and V_{GG2} = +3.5 V. At +25°C, V_{GG1} has been adjusted to achieve I_{DD} = 300 mA. Data was taken on a modified TB-AVA-223MPC+ test board using an external bias tee. See Figure 3.

